

APPENDIX A

In the following, insertions are underlined and deletions are enclosed in brackets.

11. (Amended) The method according to claim 10 [11], wherein said second undoped aluminum gallium arsenide layer has a thickness of about 50 nm.

11. (Amended) The method according to claim 10 [11], wherein said second undoped aluminum gallium arsenide layer has a thickness of about 50 nm.

LAW OFFICES OF
SKJERVEN MORRILL
MACPHERSON LLP

25 METRO DRIVE
SUITE 700
SAN JOSE, CA 95110
(408) 453-9200
FAX (408) 453-7979